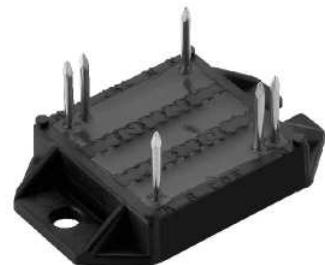
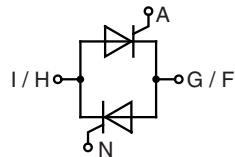


# AC Controller Modules

## Preliminary Data

**I<sub>RMS</sub>** = **112 A**  
**I<sub>TAVM</sub>** = **51 A**  
**V<sub>RRM</sub>** = **1200/1600 V**

V <sub>RSM</sub>	V <sub>RRM</sub>	
V <sub>DSM</sub>	V <sub>DRM</sub>	Typ
1300	1200	MMO 140-12io7
1700	1600	MMO 140-16io7



Symbol	Conditions	Maximum Ratings		
I <sub>RMS</sub>	T <sub>C</sub> = 85°C; 50-400 Hz (per single controller)	112	A	
I <sub>TRMS</sub>		81	A	
I <sub>TAVM</sub>	T <sub>C</sub> = 85°C; 180° sine	51	A	
I <sub>TSM</sub>	T <sub>VJ</sub> = 45°C; t = 10 ms (50 Hz) V <sub>R</sub> = 0 t = 8.3 ms (60 Hz)	1000	A	
	T <sub>VJ</sub> = 125°C; t = 10 ms (50 Hz) V <sub>R</sub> = 0 t = 8.3 ms (60 Hz)	1070	A	
		870	A	
		930	A	
I <sup>2</sup> t	T <sub>VJ</sub> = 45°C; t = 10 ms (50 Hz) V <sub>R</sub> = 0 t = 8.3 ms (60 Hz)	5000	A <sup>2</sup> s	
	T <sub>VJ</sub> = 125°C; t = 10 ms (50 Hz) V <sub>R</sub> = 0 t = 8.3 ms (60 Hz)	4810	A <sup>2</sup> s	
		3780	A <sup>2</sup> s	
		3630	A <sup>2</sup> s	
(di/dt) <sub>cr</sub>	T <sub>VJ</sub> = 125°C; repetitive, I <sub>T</sub> = 50 A f = 50 Hz; t <sub>p</sub> = 200 µs;	100	A/µs	
	V <sub>D</sub> = 2/3 V <sub>DRM</sub> ; I <sub>G</sub> = 0.45 A; di <sub>G</sub> /dt = 0.45 A/µs	500	A/µs	
(dv/dt) <sub>cr</sub>	T <sub>VJ</sub> = 125°C; V <sub>D</sub> = 2/3 V <sub>DRM</sub> ; R <sub>GK</sub> = ∞; method 1 (linear voltage rise)	1000	V/µs	
P <sub>GM</sub>	T <sub>VJ</sub> = 125°C; t <sub>p</sub> = 30 ms I <sub>T</sub> = I <sub>T(AV)M</sub> ; t <sub>p</sub> = 300 ms	10	W	
		5	W	
P <sub>GAVM</sub>		0.5	W	
V <sub>RGM</sub>		10	V	
T <sub>VJ</sub>		-40...+150	°C	
T <sub>VJM</sub>		150	°C	
T <sub>stg</sub>		-40...+125	°C	
V <sub>ISOL</sub>	50/60 Hz, RMS t = 1 min I <sub>ISOL</sub> ≤ 1 mA t = 1 s	2500	V~	
		3000	V~	
M <sub>d</sub>	Mounting torque (M4)	1.5 - 2.0	Nm	
		14 - 18	lb.in.	
Weight	Typical including screws	18	g	

Data according to IEC 60747 and refer to a single diode unless otherwise stated.

### Features

- Thyristor controller for AC (circuit W1C acc. to IEC) for mains frequency
- Isolation voltage 3000 V~
- Planar glass passivated chips
- Low forward voltage drop
- Leads suitable for PC board soldering

### Applications

- Switching and control of single and three phase AC circuits
- Light and temperature control
- Softstart AC motor controller
- Solid state switches

### Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling
- High power density
- Small and light weight

Symbol	Conditions	Characteristic Values	
		typ.	max.
$I_D, I_R$	$V_R / V_D = V_{RRM} / V_{DRM}$	$T_{VJ} = 125^\circ\text{C}$	5 mA
$V_T$	$I_T = 150 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$	1.57 V
$V_{TO}$	For power-loss calculations only	0.85 V	
$r_t$		5.60 mΩ	
$V_{GT}$	$V_D = 6 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$	1.5 V
		$T_{VJ} = -40^\circ\text{C}$	1.9 V
$I_{GT}$	$V_D = 6 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$	100 mA
		$T_{VJ} = -40^\circ\text{C}$	200 mA
$V_{GD}$	$V_D = \frac{2}{3} V_{DRM};$	$T_{VJ} = 125^\circ\text{C}$	0.2 V
$I_{GD}$			1 mA
$I_L$	$t_p = 10 \mu\text{s};$ $I_G = 0.45 \text{ A}; dI_G/dt = 0.45 \text{ A}/\mu\text{s}$	$T_{VJ} = 25^\circ\text{C}$	200 mA
$I_H$	$V_D = 6 \text{ V}; R_{GK} = \infty;$	$T_{VJ} = 25^\circ\text{C}$	100 mA
$t_{gd}$	$V_D = \frac{1}{2} V_{DRM}$	$T_{VJ} = 25^\circ\text{C}$	2 μs
	$I_G = 0.45 \text{ A}; dI_G/dt = 0.45 \text{ A}/\mu\text{s}$		
$R_{thJC}$	per thyristor; DC current	0.80 K/W	
$R_{thCH}$		0.12 K/W	
$R_{thJC}$	per module	0.40 K/W	
$R_{thCH}$		0.06 K/W	
$d_s$	Creeping distance on surface	11.2 mm	
$d_A$	Creepage distance in air	5.0 mm	
$a$	Maximum allowable acceleration	50 m/s <sup>2</sup>	

## Dimensions in mm (1 mm = 0.0394")

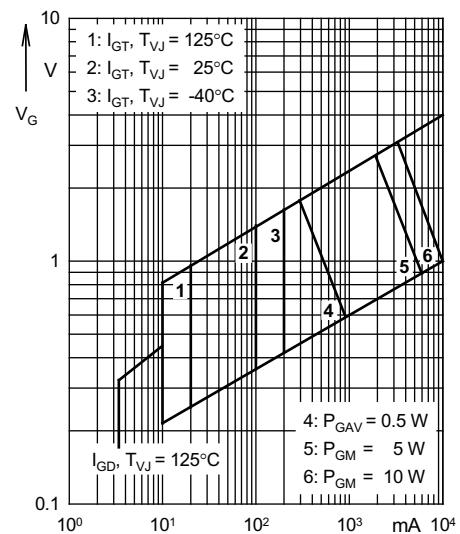
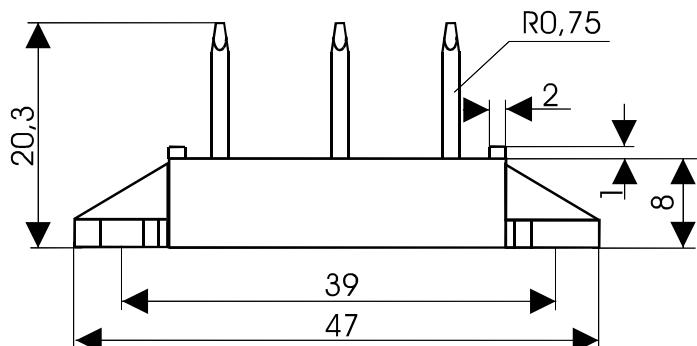
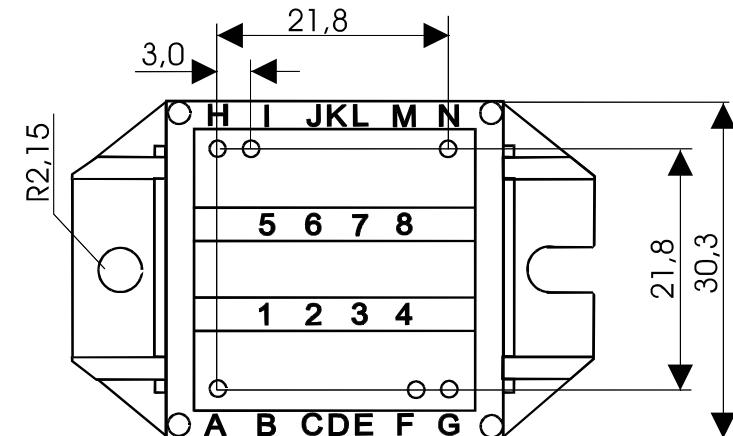


Fig. 1 Gate trigger characteristics

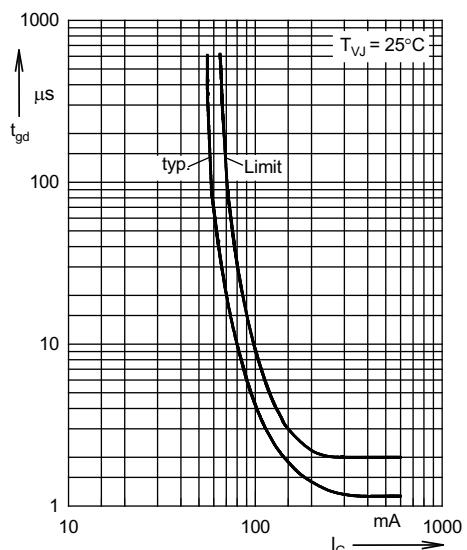


Fig. 2 Gate trigger delay time

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